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Vishay Semiconductors

Hyperfast Rectifier, 3 A FRED Pt®

eSMP® Series



Top View

Bottom View

SlimSMAW (DO-221AD)



LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS					
I _{F(AV)}	3 A				
V_R	100 V, 200 V				
V _F at I _F	0.71 V				
I _{FSM}	70 A				
t _{rr} (typ.)	16 ns				
T _J max.	175 °C				
Package	SlimSMAW (DO-221AD)				
Circuit configuration	Single				

FEATURES

- Low profile package
- · Ideal for automated placement
- · Low forward voltage drop, low power losses
- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- COMPLIANT HALOGEN FREE

AUTOMOTIVE

- AEC-Q101 qualified, class 2 whisker test
- Compatible to SOD-128 package case outline
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION / APPLICATIONS

For use in high frequency, freewheeling, DC/DC converters, PFC, and in snubber industrial, and automotive applications.

MECHANICAL DATA

Case: SlimSMAW (DO-221AD)

Molding compound meets UL 94 V-0 flammability rating

Halogen-free, RoHS-compliant

Terminals: matte tin plated leads, solderable per

J-STD-002

Polarity: color band denotes cathode end

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Peak repetitive reverse voltage VS-3EYH01HM3	V		100	V		
VS-3EYH02HM3	- V _{RRM}		200	V		
Average rectified forward current	I _{F(AV)} (1)	T _C = 137 °C	3	А		
Non-repetitive peak surge current	I _{FSM}	T _J = 25 °C, 10 ms sine pulse wave	70			
Operating junction and storage temperatures	T _J , T _{Stg}		-55 to +175	°C		

Note

⁽¹⁾ Mounted on infinite heatsink

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)							
PARAMETER		SYMBOL	DL TEST CONDITIONS		TYP.	MAX.	UNITS
Breakdown voltage, blocking	VS-3EYH01HM3	V_{BR}, V_{R}	I _R = 100 μA	100	-	-	V
voltage	VS-3EYH02HM3		Ι _R = 100 μΑ	200	-		
Forward voltage, per diode		V	I _F = 3 A	-	0.86	0.95	V
		V _F	I _F = 3 A, T _J = 150 °C	-	0.71	0.79	
Reverse leakage current, per diode		1	$V_R = V_R$ rated	-	-	2	
		I _R	T _J = 150 °C, V _R = V _R rated	-	-	20	μA
Junction capacitance		C _T	V _R = 200 V	-	16	-	pF



VS-3EYH01HM3, VS-3EYH02HM3

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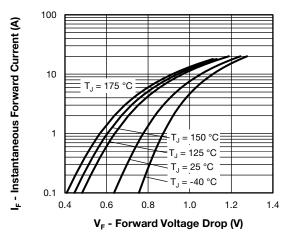
DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Reverse recovery time		$I_F = 1.0 \text{ A}, dI_F/dt =$	= 50 A/μs, V _R = 30 V	-	22	-	
		$I_F = 1.0 \text{ A}, dI_F/dt = 100 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		-	16	-	ns
	t _{rr}	I _F = 0.5 A, I _R = 1A, I _{rr} = 0.25 A		-	-	30	
		T _J = 25 °C	I _F = 3 A,	-	18	-	
		T _J = 125 °C		-	30	-	
Peak recovery current		T _J = 25 °C		-	2.5	-	^
	I _{RRM}	T _J = 125 °C	$dI_F/dt = 200 \text{ A/}\mu\text{s},$ $V_R = 100 \text{ V}$	-	4	-	Α
Reverse recovery charge		T _J = 25 °C		-	23	-	0
	Q _{rr}	T _J = 125 °C	1	-	60	-	nC

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range		T _J , T _{Stg}		-55	-	175	°C
Thermal resistance, junction to mount		R _{thJM} ⁽¹⁾	Infinite heatsink	-	12	15	
Thermal resistance, junction to ambient		R _{thJA}	Device mounted on FR4 PCB, 2 oz. standard footprint	-	120	150	°C/W
Marking dayioo	VS-3EYH01HM3		Case style SlimSMAW (DO-221AD)	3H1			
Marking device	VS-3EYH02HM3		Case style SilitiSiviAW (DO-22 IAD)	3H2			

Note

⁽¹⁾ Thermal resistance junction to mount follows JEDEC® 51-14 transient dual interface test method (TDIM)

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100 I_R - Reverse Current (µA) 10 150 °C 1 125 °C 0.1 25 °C 0.01 0.001 0.0001 50 100 150 200 **V_R** - Reverse Voltage (V)

Fig. 1 - Typical Forward Voltage Drop Characteristics

Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

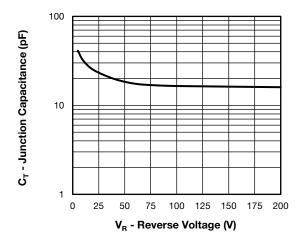


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

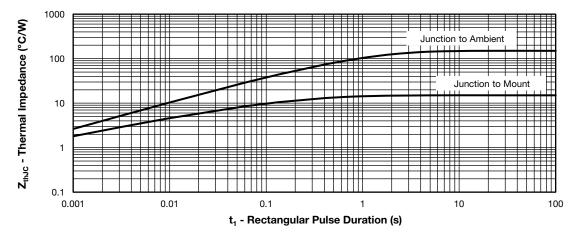


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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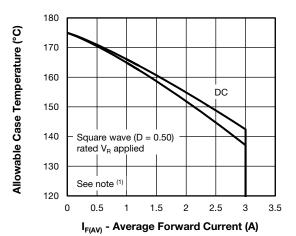
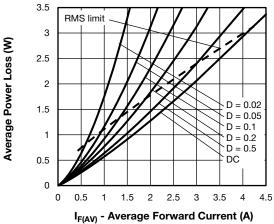
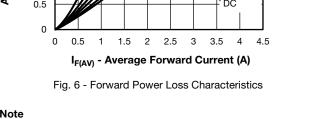


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current







⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; Pd = forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 5); Pd_{REV} = inverse power loss = $V_{R1} \times I_R (1 - D)$; I_R at V_{R1} = rated V_R

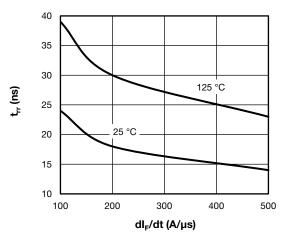


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

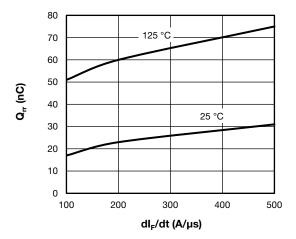


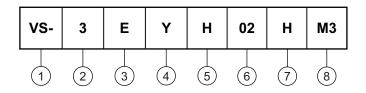
Fig. 8 - Typical Stored Charge vs. dl_F/dt

VS-3EYH01HM3, VS-3EYH02HM3

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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (3 = 3 A)

Circuit configuration:

E = single diode

4 - Y = SlimSMAW (DO-221AD)

5 - Process type,

H = hyperfast recovery

6 - Voltage code (02 = 200 V)

7 - H = AEC-Q101 qualified

8 - M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)							
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	PACKAGING DESCRIPTION			
VS-3EYH01HM3/H	0.033	Н	3500	7"diameter plastic tape and reel			
VS-3EYH01HM3/I	0.033	I	14 000	13"diameter plastic tape and reel			
VS-3EYH02HM3/H	0.033	Н	3500	7"diameter plastic tape and reel			
VS-3EYH02HM3/I	0.033	1	14 000	13"diameter plastic tape and reel			

LINKS TO RELATED DOCUMENTS					
Dimensions <u>www.vishay.com/doc?96582</u>					
Part marking information	www.vishay.com/doc?95562				
Packaging information	www.vishay.com/doc?88869				
SPICE model	www.vishay.com/doc?96586				



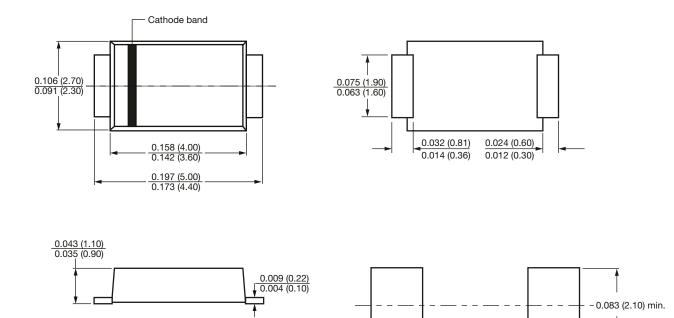
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0.055 (1.40) min.

SlimSMAW (DO-221AD)

DIMENSIONS in inches (millimeters)

SlimSMAW (DO-221AD)



0.055 (1.40) min.

Mounting pad layout

0.118 (3.00) max.

0.228 (5.80) ref.



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